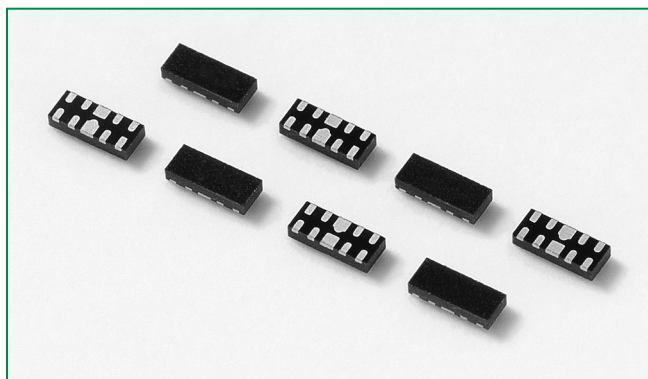
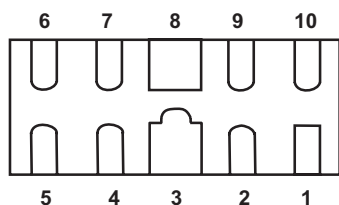


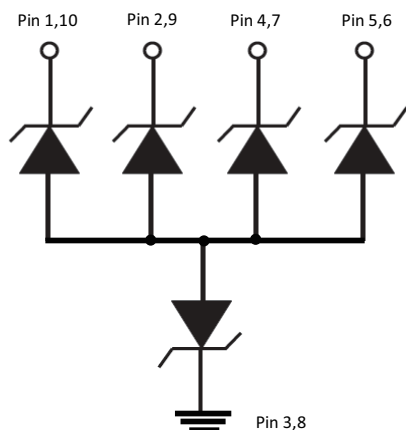
SP1064 Series 8.5pF, 15KV Diode Array



Pinout



Functional Block Diagram



Description

Zener diodes fabricated in a proprietary silicon avalanche technology protect each I/O pin to provide a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in IEC 61000-4-2 international standard (Level 4, $\pm 8\text{kV}$ contact discharge) without performance degradation. Their very low loading capacitance also makes them ideal for protecting high speed signal pins.

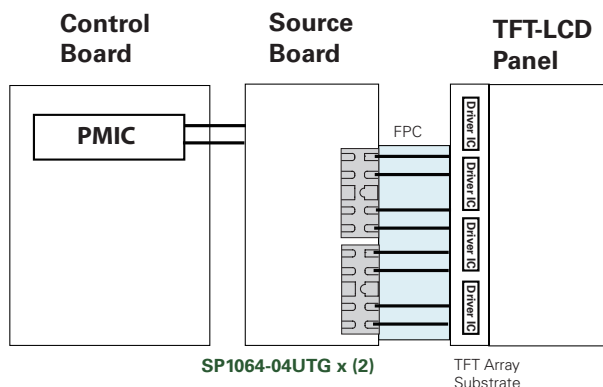
Features

- ESD, IEC 61000-4-2, $\pm 15\text{kV}$ contact, $\pm 20\text{kV}$ air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, IEC 61000-4-5, 2nd edition, 2A ($t_p=8/20\mu\text{s}$)
- Low capacitance of 8.5pF (TYP) per I/O
- Low leakage current of $0.05\mu\text{A}$ (TYP) at 60V
- Small form factor μDFN (JEDEC MO-229) package saves board space
- Lead free and RoHS compliant

Applications

- LCD/PDP TVs
- DVD Players
- Desktops
- MP3/PMP
- Set Top Boxes
- Mobile Phones
- Notebooks
- Digital Cameras

Application Example



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current ($t_p=8/20\mu s$)	2.0	A
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics ($T_{OP}=25^\circ C$)

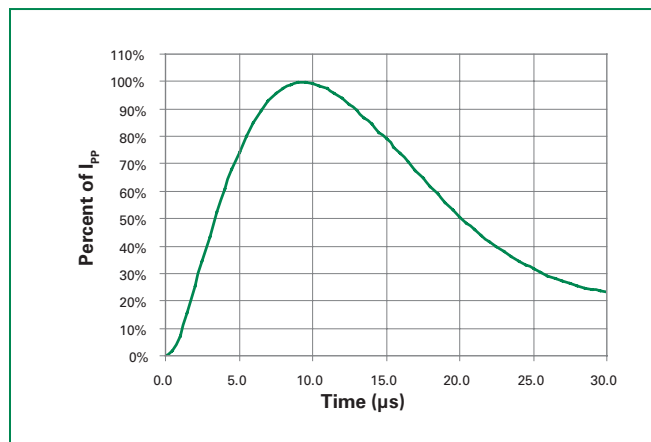
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			60	V
Reverse Leakage Current	I_{LEAK}	$V_R=60V$, Any I/O to GND		0.05		μA
Clamp Voltage ¹	V_C	$I_{PP}=1A$, $t_p=8/20\mu s$, Fwd		81		V
		$I_{PP}=2A$, $t_p=8/20\mu s$, Fwd		95		V
Dynamic Resistance ³	R_{DYN}	TLP, $t_p=100ns$, I/O to GND		4		Ω
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact)	± 15			kV
		IEC 61000-4-2 (Air)	± 20			kV
Line Capacitance ^{1,2}	C_L	Reverse Bias=0V; f=1MHz		8.5		pF

Note 1: Parameter is guaranteed by design and/or device characterization.

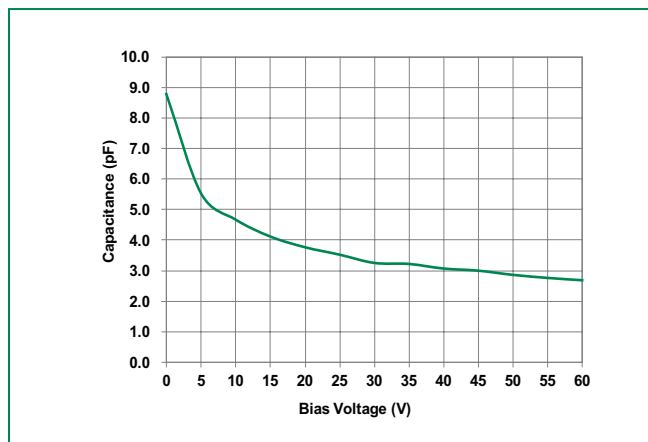
Note 2: Test equipment accuracy $\pm 50ff$.

Note 3: Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window $t_1=70ns$ to $t_2=90ns$

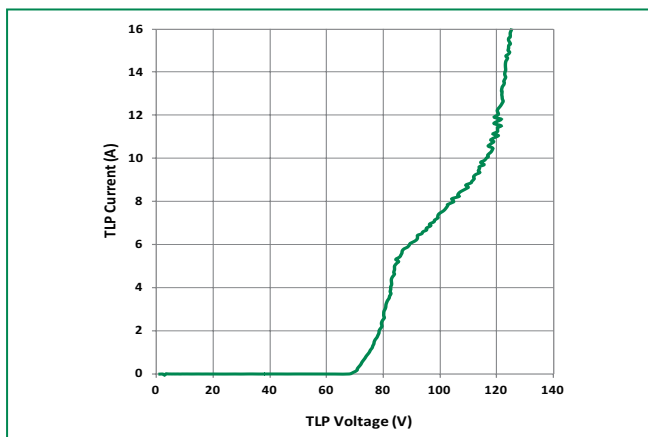
8/20 μs Pulse Waveform



Capacitance vs. Reverse Bias

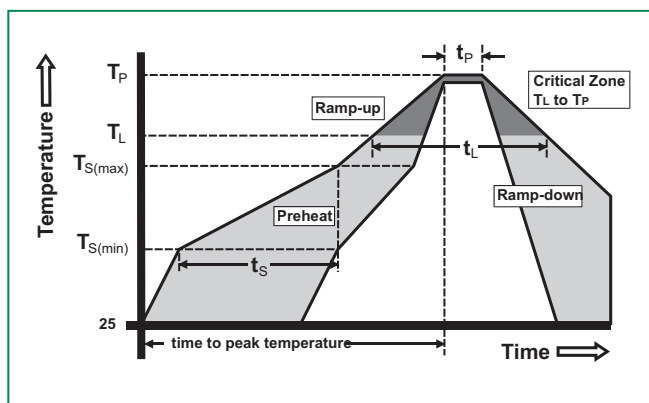


Transmission Line Pulsing (TLP) Plot



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_P)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		260°C



Product Characteristics

Lead Plating	Tin
Lead Material	Copper Alloy
Lead Coplanarity	0.004 inches(0.102mm)
Substrate material	Silicon
Body Material	Molded Epoxy
Flammability	UL 94 V-0
MSL Rating	Level 1

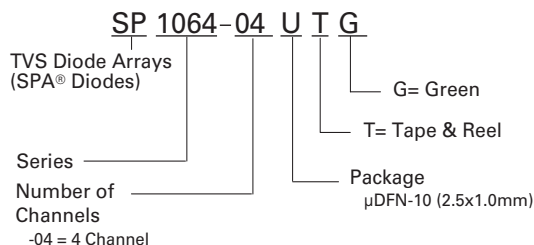
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

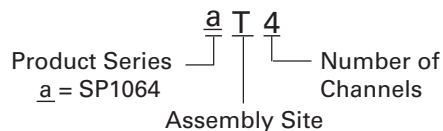
Ordering Information

Part Number	Package	Marking	Min. Order Qty.
SP1064-04UTG	μDFN-10	aT4	3000

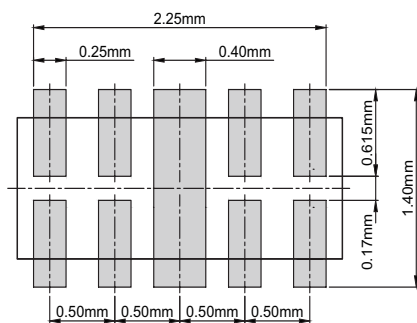
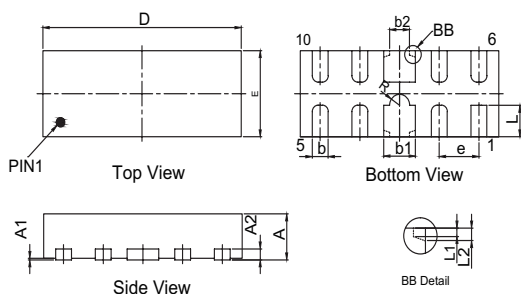
Part Numbering System



Part Marking System



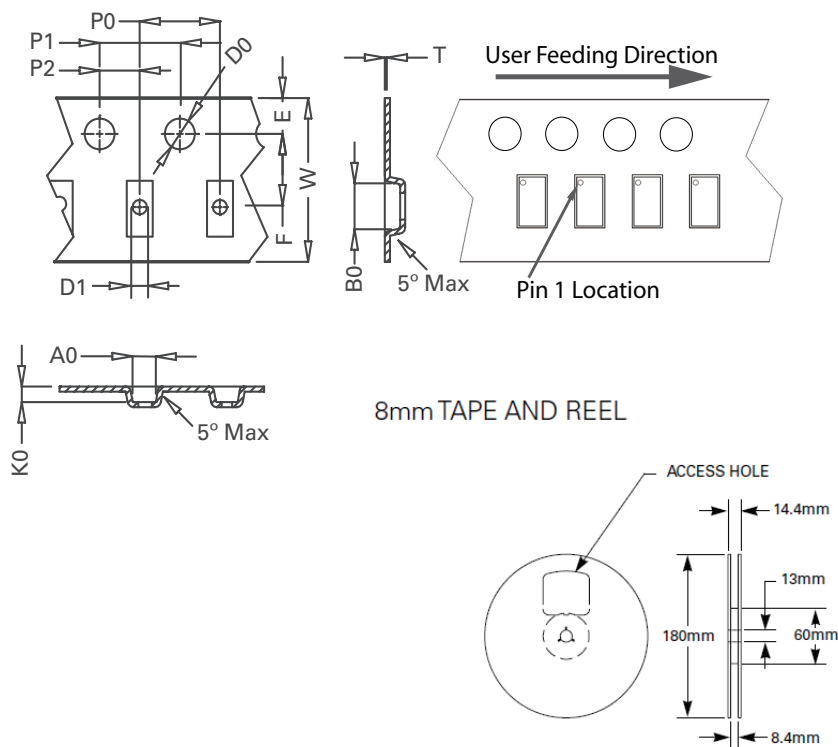
Package Dimensions — μDFN-10 (2.5x1.0x0.5mm)



Recommended Soldering Layout

Package	μDFN-10 (2.5x1.0x0.5mm)			
JEDEC	MO-229			
Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A	0.45	0.55	0.018	0.022
A1	0.00	0.05	0.000	0.002
A2	0.10	0.20	0.004	0.008
b	0.15	0.25	0.006	0.010
b1	0.35	0.45	0.014	0.018
b2	0.25 REF (Optional)		0.010 REF (Optional)	
D	2.40	2.60	0.098	0.106
E	0.90	1.10	0.037	0.045
L	0.30	0.45	0.012	0.018
e	0.50 BSC		0.020 BSC	
R	0.05	0.15	0.002	0.006

Embossed Carrier Tape & Reel Specification — μ DFN-10



Package	μ DFN-10 (2.5x1.0x0.5mm)
Symbol	Millimeters
A0	1.30 +/- 0.10
B0	2.83 +/- 0.10
D0	$\varnothing$ 1.50 + 0.10
D1	$\varnothing$ 1.00 + 0.25
E	1.75 +/- 0.10
F	3.50 +/- 0.05
K0	0.65 +/- 0.10
P0	4.00 +/- 0.10
P1	4.00 +/- 0.10
P2	2.00 +/- 0.05
T	0.254 +/- 0.02
W	8.00 + 0.30 /- 0.10